EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|----------|------|--|---|---------------------|---------|------------------|
| Lı | 1 | ("20040185599").PN. | US-PGPUB | OR | OFF | 2006/03/27 13:40 |
| L2 | 3764 | (semiconductor with (dry adj etch\$5)) and metal and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR . | ON | 2006/03/27 13:49 |
| L3 | 173 | (semiconductor near (dry adj etch\$5)) and metal and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/27 13:49 |
| L4 | 60 | (semiconductor near (dry adj etch\$5)) and (metal adj (layer or film)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/27 13:50 |
| S5 | 1 | ("6153520").PN. | USPAT; USOCR | OR | OFF | 2004/10/25 10:43 |
| S9 | 1 | ("6524939").PN. | USPAT; USOCR | OR | OFF | 2005/09/22 14:22 |
| S12 | 7 | (("6291839") or ("6078064") or ("5804839") or ("6008539") or ("6335218") or ("6258618") or ("5438006")).PN. | USPAT; USOCR | OR | OFF | 2004/10/25 10:52 |
| S13 | 1 | "5656832".PN. | USPAT | OR | ON | 2004/10/21 14:56 |
| S15 | 0 | (438/671.ccls. with (dry adj etch\$5)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/18 07:08 |
| S16 | 0 | ("438"/\$.ccls. with (dry adj etch\$5)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/18 07:08 |
| S17 | 0 | ("257"/\$.ccls. with (dry adj etch\$5)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/18 07:07 |

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| S18 | 197 | (438/671).CCLS. | US-PGPUB; | OR | OFF | 2005/04/18 07:07 |
|---------|------|--|---|----|-----|------------------|
| | | | USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | | | |
| S19 | 0 | ((438/671.ccls.) with (dry adj etch\$5)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/18 07:08 |
| S20 | 8999 | (semiconductor with (dry adj etch\$5)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/22 13:38 |
| S21 | 24 | (semiconductor with (dry adj etch\$5) with (light adj emitting adj device)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/27 13:40 |
| S22 | 15 | (semiconductor with (dry adj etch\$5) with (light adj emitting adj device)) and metal and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/03/27 13:49 |
| S23 | 3 | (semiconductor with metal with (dry adj etch\$5) with (light adj emitting adj device)) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/04/18 07:10 |
| S24 | 134 | (((semiconductor) with ((silicon or ("S")) adj (layer or film))) and ((metal adj (film or layer)) with (dry adj etch\$5))) and @ad<="20010927" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/09/22 13:40 |
| S25 | 1 | ("6777294").PN. | USPAT; USOCR | OR | OFF | 2005/09/22 14:33 |
| S26 | 1 | ("6790718").PN. | USPAT; USOCR | OR | OFF | 2005/09/22 14:48 |